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Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 10 A



PRIMARY CHARACTERISTICS								
I _{F(AV)}	10 A							
V _R	1000 V, 1200 V							
V _F at I _F	1.33 V							
I _{FSM}	140 A							
t _{rr}	80 ns							
T _J max.	150 °C							
Snap factor	0.6							
Package	TO-220AC 2L							
Circuit configuration	Single							

FEATURES

- Glass passivated pellet chip junction
- 150 °C max operating junction temperature
- Low forward voltage drop and short reverse recovery time
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-10ETF1... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
V _{RRM}		1000 to 1200	V					
I _{F(AV)}	Sinusoidal waveform	10	^					
I _{FSM}		140	A					
t _{rr}	1 A, 100 A/µs	80	ns					
V _F	10 A, T _J = 25 °C	1.33	V					
TJ		-40 to +150	°C					

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA						
VS-10ETF10-M3	1000	1100	4						
VS-10ETF12-M3	1200	1200	4						

ABSOLUTE MAXIMUM RATINGS								
PARAMETER SYMBOL TEST CONDITIONS VALUES UNITS								
Maximum average forward current	I _{F(AV)}	T _C = 125 °C, 180° conduction half sine wave	10					
Maximum peak one cycle	1	10 ms sine pulse, rated V _{RRM} applied	115	Α				
non-repetitive surge current	I _{FSM}	10 ms sine pulse, no voltage reapplied	140					
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	66	A ² s				
Waxiinum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied 94		7-5				
Maximum I ² √t for fusing	I²√t	t = 0.1 to 10 ms, no voltage reapplied	940	A²√s				



ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS				
Maximum forward voltage drop	V_{FM}	10 A, T _J = 25 °C		1.33	V				
Forward slope resistance	r _t	T _{.1} = 150 °C		22.9	mΩ				
Threshold voltage	V _{F(TO)}	1J = 150 C		0.96	V				
Maximum reverse leakage current		T _J = 25 °C	V _R = Rated V _{RRM}	0.1	mA				
iviaximum reverse leakage current	IRM	T _J = 150 °C	v _R = nateu v _{RRM}	4	IIIA				

RECOVERY CHARACTERISTICS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •				
Reverse recovery time	t _{rr}	In at 10 Anu	310	ns	I _{FM} t				
Reverse recovery current	I _{rr}	I _F at 10 A _{pk} 25 A/μs	4.7	Α	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \				
Reverse recovery charge	Q _{rr}	25 °C	1.05	μC	dir/ dt/ Q _{rr}				
Typical snap factor	S		0.6		I _{RM(REC)}				

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to +150	°C				
Maximum thermal resistar junction to case	nce	R _{thJC}	DC operation	1.5					
Maximum thermal resistance junction to ambient		R _{thJA}		62	°C/W				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.5					
Approximate weight				2	g				
Approximate weight				0.07	OZ.				
Mounting torque	minimum			6 (5)	kgf ⋅ cm				
Mounting torque	maximum			12 (10)	(lbf \cdot in)				
Marking device			Case style TO-220AC 2L (JEDEC)	10ETF10 10ETF12					

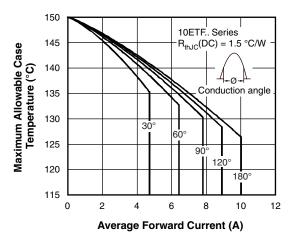


Fig. 1 - Current Rating Characteristics

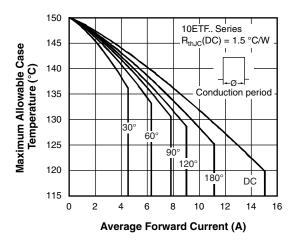


Fig. 2 - Current Rating Characteristics

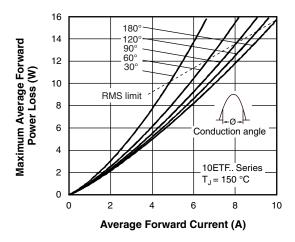


Fig. 3 - Forward Power Loss Characteristics

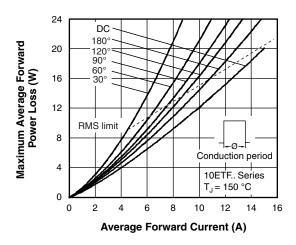


Fig. 4 - Forward Power Loss Characteristics

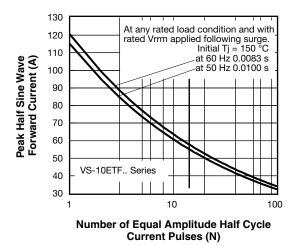


Fig. 5 - Maximum Non-Repetitive Surge Current

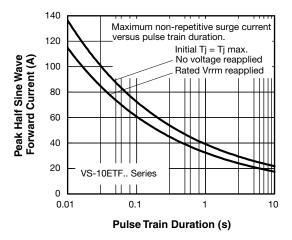


Fig. 6 - Maximum Non-Repetitive Surge Current

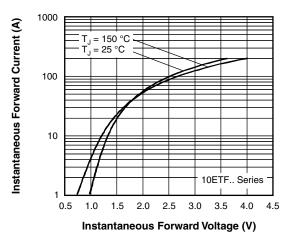


Fig. 7 - Forward Voltage Drop Characteristics

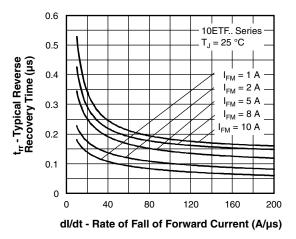


Fig. 8 - Recovery Time Characteristics, $T_J = 25 \, ^{\circ}\text{C}$

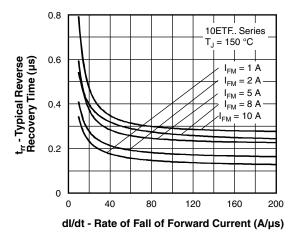


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

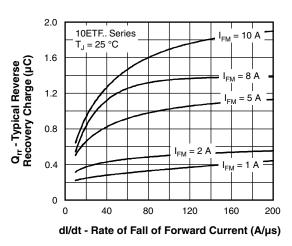


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

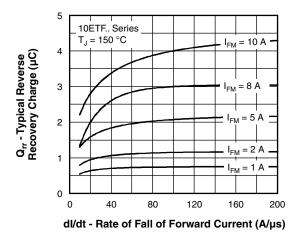


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

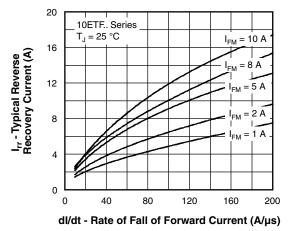


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

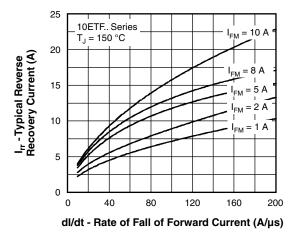


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

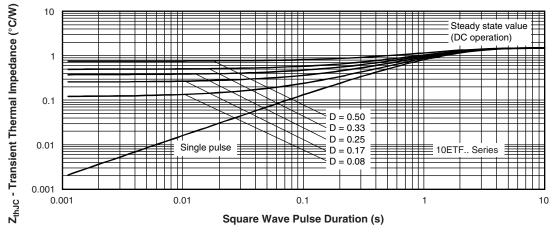
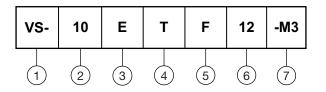


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Current rating (10 = 10 A)

3 - Circuit configuration:

E = single

4 - Package:

T = 2L TO-220AC

5 - Type of silicon:

F = fast soft recovery rectifier

Voltage code x 100 = V_{RRM} 10 = 1000 V 12 = 1200 V

7 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

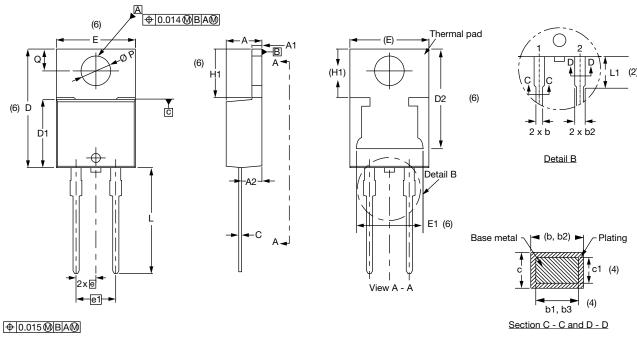
ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-10ETF10-M3	50	Antistatic plastic tube						
VS-10ETF12-M3	50	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?96156</u>						
Part marking information	www.vishay.com/doc?95391					



TO-220AC 2L

DIMENSIONS in millimeters and inches



Lead tip

Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIN	METERS INCHES		NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES	
STWIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
с1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355								

Notes

- $^{(1)}$ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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